

# 2SC3324GRTE85LF

# 2SC3324GRTE85LF Information

www.Eelseper.com		2SC3324GRTE85LF Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single		
	Description	TRANS NPN 120V 0.1A S-MINI	RE-26-041	
	Package	TO-236-3, SC-59, SOT-23-3		
		For the pricing/inventory/lead time, please contact		
		us		
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote	

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# 2SC3324GRTE85LF Specifications

Manufacturer Part Number	2SC3324GRTE85LF	
Manufacturer	Toshiba Semiconductor and Storage	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-236-3, SC-59, SOT-23-3	
Series	-	
Transistor Type	NPN	
Current - Collector (Ic) (Max)	100mA	
Voltage - Collector Emitter Breakdown (Max)	120V	
Vce Saturation (Max) @ Ib, Ic	300mV @ 1mA, 10mA	
Current - Collector Cutoff (Max)	100nA (ICBO)	
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2mA, 6V	
Power - Max	150mW	
Frequency - Transition	100MHz	
Operating Temperature	125°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	TO-236-3, SC-59, SOT-23-3	
Supplier Device Package	TO-236	
	Report errors?	

# 2SC3324GRTE85LF Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

## 2SC3324GRTE85LF Payment Methods



If you have any question about 2SC3324GRTE85LF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com